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Approved for use through 10/31/2002. OMB 0651-0031

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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

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**Complete if Known**

Application Number	09/879,090
Filing Date	June 13, 2001
First Named Inventor	Satoshi YOSHIMOTO
Group Art Unit	2814
Examiner Name	H. Trinh
Attorney Docket Number	0756-2326

Sheet 1 of 4

**U.S. PATENT DOCUMENTS**

Examiner Initials <sup>1</sup>	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			
WZ		6,492,659		Yamazaki et al.	12/10/2002	
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		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>2</sup> (if known)				
WZ		JP	06-005862			01/14/1994		Abst.
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		JP	07-321339			12/08/1995		Abst.
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**OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS**

Examiner Initials <sup>1</sup>	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
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		Baker, Jr., et al., <i>Field Effect Transistor</i> , IBM Technical Disclosure Bulletin, Vol. 11, No. 7., Page 849, December 1, 1968.	
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		Aragona, <i>Dislocation Etch for (100) Planes of Silicon</i> , J. Electrochem. Soc., Vol. 119, No. 7, Pages 948-951, July 1, 1972.	

Examiner Signature	H. Trinh	Date Considered	5/16/25
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				Filing Date	June 13, 2001
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				Examiner Name	H. Trinh
				Attorney Docket Number	0756-2326

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[Signature]		4,020,319		Shepard et al.	04/26/1977	
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		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)				
[Signature]		JP	09-186336			07/15/1997		Full
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Examiner Signature	<i>Vicki Trinh</i>	Date Considered	5/18/05
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Examiner  
Signature*[Handwritten Signature]*

Date

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05/16/05

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## **Complete if Known**

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Filing Date	June 13, 2001
First Named Inventor	Satoshi YOSHIMOTO
Group Art Unit	2814
Examiner Name	H. Trinh
Attorney Docket Number	0756-2326

U.S. PATENT DOCUMENTS					
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Examiner Signature	<i>H. Trinh</i>	Date Considered	05/16/05
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(Rev. 8-83)U.S. Department of Commerce  
Patent and Trademark Office

Atty Docket 0756-2326

Serial No. 09/879,090

## INFORMATION DISCLOSURE STATEMENT

JUL 31 2001

Applicants: Satoshi YOSHIMOTO

Filing Date: June 13, 2001

Group Art Unit:  
Unassigned

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Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
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WZ	Mariucci et al., "Lateral Growth Control in Excimer Laser Crystallized Polysilicon", pp. 137-142, 1999, Thin Solid Films 337
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Form PTO-1449 (Rev. 8-83)		U.S. Department of Commerce Patent and Trademark Office		Atty Docket 0756-2326	Serial No. 09/879,090
INFORMATION DISCLOSURE STATEMENT				Applicants: Satoshi YOSHIMOTO	
				Filing Date: June 13, 2001	Group Art Unit: Unassigned
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)					
Examiner Initial					
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Examiner	AA <i>W. H. Smith</i>			Date Considered 05/16/05	
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